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Form PTO-1449 (Rev. 2-32)		U.S. Department of Commerce Patent & Trademark Office	Atty. Docket No. Q61184	Serial No.: NOT YET ASSIGNED Confirmation No.: NOT YET ASSIGNED		
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)		Applicant: Toshitaka AGANO				
			Filing Date: April 2, 2001	Group:		
U.S. PATENT DOCUMENTS						
Examiner Initials	Document Number	Date	Name	Class	Sub-Class	Filing Date (if appropriate)
<i>HP</i>	4,803,359	02/07/89	HOSOI et al	250	327.2	
FOREIGN PATENT DOCUMENTS						
	Document	Date	Country	Class	Sub-class	Translation Yes/No
<i>HP</i>	59-211263	11/30/84	JP	H01L	27/14	<i>NOT PROVIDED</i>
	2-164067	06/25/90	JP	H01L	27/146	
	1-216290	08/30/89	JP	G01T	1/24	
	0 898 421 A2	02/24/99	EP	H04N	5/30	
	9-222114	08/26/97	JP	F16B	47/00	<i>NOT PROVIDED</i>
<i>↓</i>	92/06501	04/16/92	WO	H01L	27/14	
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)						
<i>HP</i>	Material Parameters In Thick Hydrogenated Amorphous Silicon Radiation Detectors, University of California, Berkeley					
	IEEE, Vol. 36, No. 2, April 1989, Metal/Amorphous Silicon Multilayer Radiation Detectors, YUJIRO NARUSE and TAMOTSU HATAYAMA					
	Abstract, 02-164067, 06/25/90					
	Abstract, 01-216290, 08/30/89					
EXAMINER: <i>HP</i>	DATE CONSIDERED: <i>8/22/05</i>					
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